

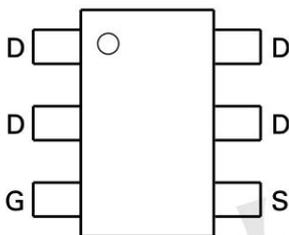
## Product Summary

- 60V/ 5A  
 $R_{DS(ON)} = 25m\Omega (Typ) @ V_{GS} = -10V$   
 $R_{DS(ON)} = 30m\Omega (Typ) @ V_{GS} = -4.5V$
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

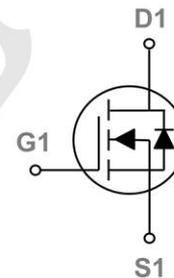
## Application

- DC-DC Converters.
- Load Switch.
- Power Management.

## Package and Pin Configuration



## Circuit diagram



## Marking:



## Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

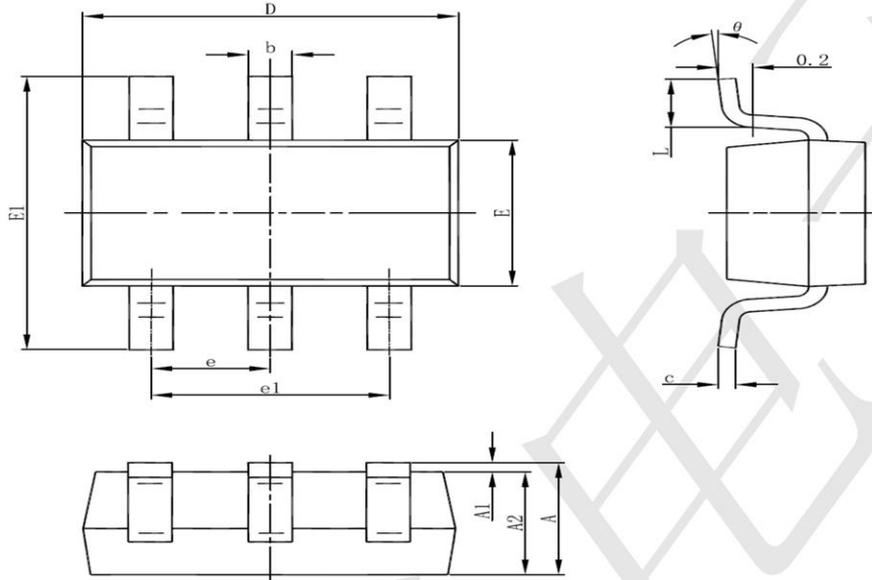
| Parameter  | Symbol          | Value    | Unit         |
|--|-----------------|----------|--------------|
| Drain-Source Voltage                                 | $V_{DS}$        | 60       | V            |
| Gate-Source Voltage                                  | $V_{GS}$        | $\pm 20$ | V            |
| Continuous Drain Current                             | $I_D$           | 5        | A            |
| Pulsed Drain Current (note 1)                        | $I_{DM}$        | 30       | A            |
| Power Dissipation                                    | $P_D$           | 1.7      | A            |
| Thermal Resistance from Junction to Ambient (note 2) | $R_{\theta JA}$ | 106      | $^\circ C/W$ |
| Junction Temperature                                 | $T_J$           | 150      | $^\circ C$   |
| Storage Temperature                                  | $T_{STG}$       | -55~+150 | $^\circ C$   |

**Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)**

| Parameter  | Symbol               | Test conditions  | Min  | Typ | Max  | Unit |
|--|----------------------|--|------|-----|------|------|
| <b>Static Characteristics</b>                      |                      |  |      |     |      |      |
| Drain-Source Breakdown Voltage                     | V <sub>(BR)DSS</sub> | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA   | 60   |     |      | V    |
| Gate-Threshold Voltage <sup>(Note3)</sup>          | V <sub>GS(th)</sub>  | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA   | 1.0  |     | 3.0  | V    |
| Gate-Body Leakage Current                          | I <sub>GSS</sub>     | V <sub>GS</sub> =± 20V, V <sub>DS</sub> =0V  |      |     | ±100 | nA   |
| Zero Gate Voltage Drain Current                    | I <sub>DSS</sub>     | V <sub>DS</sub> =60V, V <sub>GS</sub> =0V  |      |     | 1    | μA   |
| Drain-Source On-Resistance <sup>(Note3)</sup>      | R <sub>DS(on)</sub>  | V <sub>GS</sub> =10V, I <sub>D</sub> =3A   |      | 25  | 29   | mΩ   |
|  |                      | V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A  |      | 30  | 35   |      |
| Forward Transconductance <sup>(Note3)</sup>        | g <sub>fs</sub>      | V <sub>DS</sub> =5V, I <sub>D</sub> =4.5A  | 11   |     |      | S    |
| <b>Dynamic Characteristics<sup>(Note4)</sup></b>   |                      |  |      |     |      |      |
| Input Capacitance                                  | C <sub>iss</sub>     | V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f=1MHz  |      | 500 |      | pF   |
| Output Capacitance                                 | C <sub>oss</sub>     |  | 60   |     |      |      |
| Reverse Transfer Capacitance                       | C <sub>rss</sub>     |  | 25   |     |      |      |
| <b>Switching Characteristics<sup>(Note4)</sup></b> |                      |  |      |     |      |      |
| Total Gate Charge                                  | Q <sub>g</sub>       | V <sub>DS</sub> =48V, V <sub>GS</sub> =10V, I <sub>D</sub> =15A  |      | 12  |      | nC   |
| Gate-Source Charge                                 | Q <sub>gs</sub>      |  | 4.1  |     |      |      |
| Gate-Drain Charge                                  | Q <sub>gd</sub>      |  | 4.5  |     |      |      |
| Turn-on Delay Time                                 | t <sub>d(on)</sub>   | V <sub>DD</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A, R <sub>G</sub> =3Ω, R <sub>L</sub> =6.7Ω |      | 5.0 |      | ns   |
| Turn-on Rise Time                                  | t <sub>r</sub>       |  | 2.6  |     |      |      |
| Turn-off Delay Time                                | t <sub>d(off)</sub>  |  | 16.1 |     |      |      |
| Turn-off Fall Time                                 | t <sub>f</sub>       |  | 2.3  |     |      |      |
| <b>Drain-Source Diode Characteristics</b>          |                      |  |      |     |      |      |
| Diode Forward Voltage <sup>(Note3)</sup>           | V <sub>SD</sub>      | V <sub>GS</sub> =0V, I <sub>S</sub> =20A   |      |     | 1.2  | V    |
| Diode Forward Current <sup>(Note2)</sup>           | I <sub>S</sub>       |  |      |     | 20   | A    |
| Reverse Recovery Time                              | t <sub>rr</sub>      | I <sub>F</sub> =20A, di/dt=100A/μs <sup>(Note4)</sup>  |      | 35  |      | nS   |
| Reverse Recovery Charge                            | Q <sub>rr</sub>      |  |      |     | 53   |      |
| Forward Turn-On Time                               | t <sub>on</sub>      | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)                                     |      |     |      |      |



SOT23-6 Package Information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | 1.050                     | 1.250 | 0.041                | 0.049 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 1.050                     | 1.150 | 0.041                | 0.045 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.100                     | 0.200 | 0.004                | 0.008 |
| D      | 2.820                     | 3.020 | 0.111                | 0.119 |
| E      | 1.500                     | 1.700 | 0.059                | 0.067 |
| E1     | 2.650                     | 2.950 | 0.104                | 0.116 |
| e      | 0.950(BSC)                |       | 0.037(BSC)           |       |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.300                     | 0.600 | 0.012                | 0.024 |
| theta  | 0°                        | 8°    | 0°                   | 8°    |

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